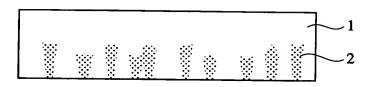
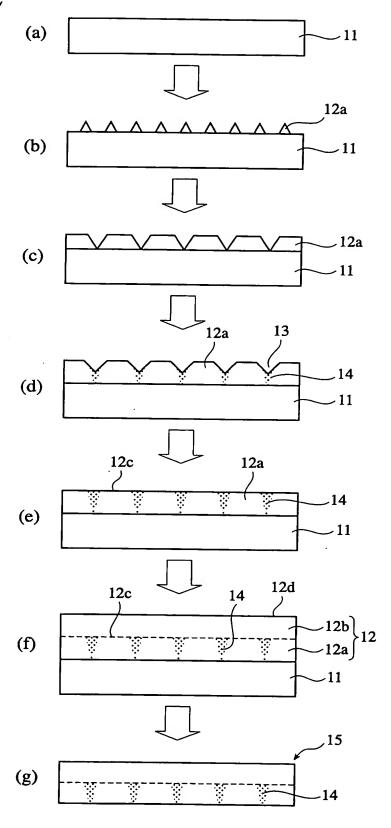
Masatomo SHIBATA
III-V NITRIDE SEMICONDUCTOR SUBSTRATE
AND ITS PRODUCTION METHOD
Filed: March 31, 2004
SUGHRUE Reference No. Q80822
Sheet 1 of 9

Fig. 1



Masatomo SHIBATA
III-V NITRIDE SEMICONDUCTOR SUBSTRATE
AND ITS PRODUCTION METHOD
Filed: March 31, 2004
SUGHRUE Reference No. Q80822
Sheet 2 of 9

Fig. 2



Masatomo SHIBATA
III-V NITRIDE SEMICONDUCTOR SUBSTRATE
AND ITS PRODUCTION METHOD
Filed: March 31, 2004
SUGHRUE Reference No. Q80822
Sheet 3 of 9

Fig. 3

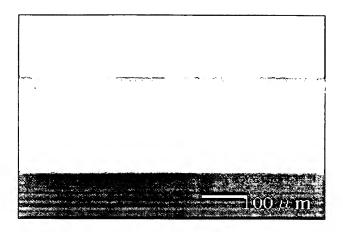
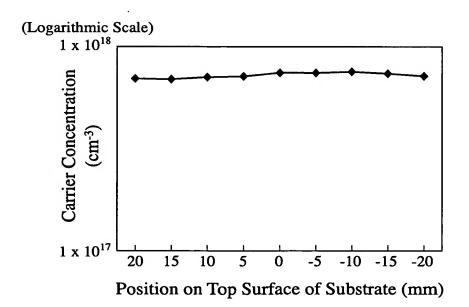


Fig. 4



Masatomo SHIBATA
III-V NITRIDE SEMICONDUCTOR SUBSTRATE
AND ITS PRODUCTION METHOD
Filed: March 31, 2004
SUGHRUE Reference No. Q80822
Sheet 4 of 9

Fig. 5

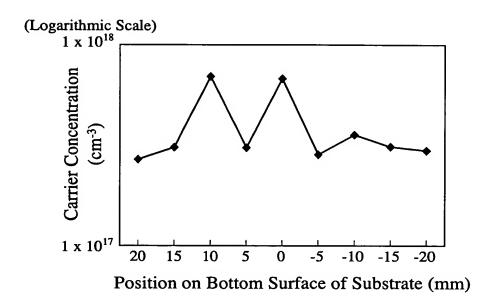
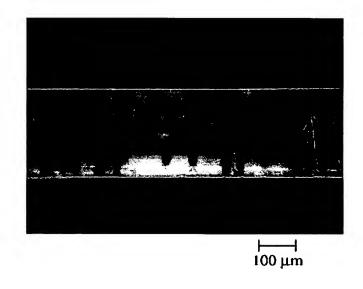
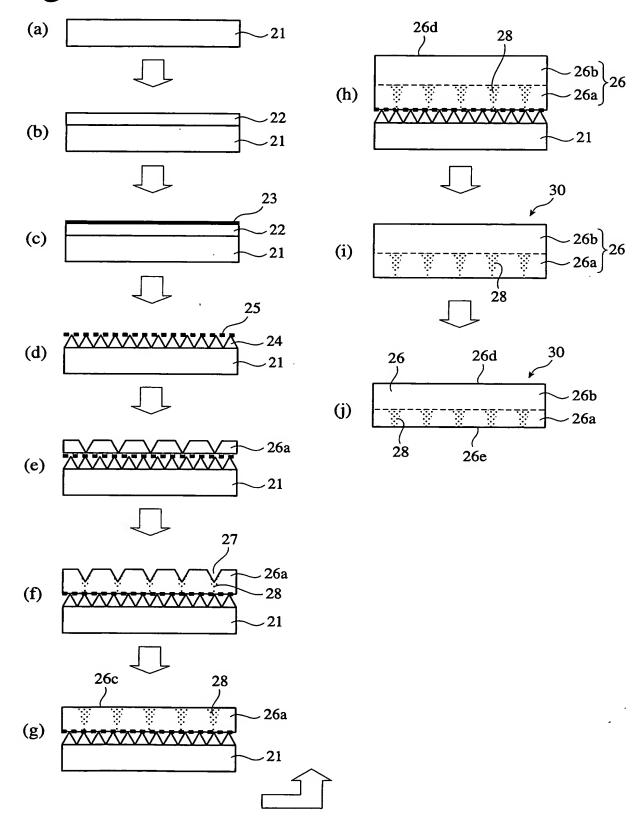


Fig. 6

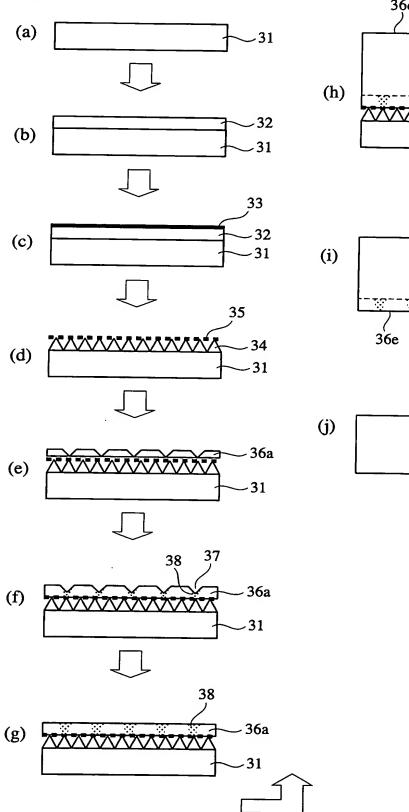


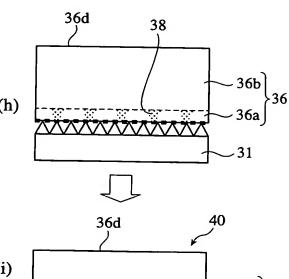
Masatomo SHIBATA
III-V NITRIDE SEMICONDUCTOR SUBSTRATE
AND ITS PRODUCTION METHOD
Filed: March 31, 2004
SUGHRUE Reference No. Q80822
Sheet 5 of 9



Masatomo SHIBATA
III-V NITRIDE SEMICONDUCTOR SUBSTRATE
AND ITS PRODUCTION METHOD
Filed: March 31, 2004
SUGHRUE Reference No. Q80822
Sheet 6 of 9

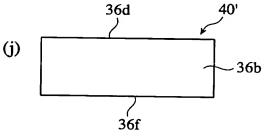
Fig. 8



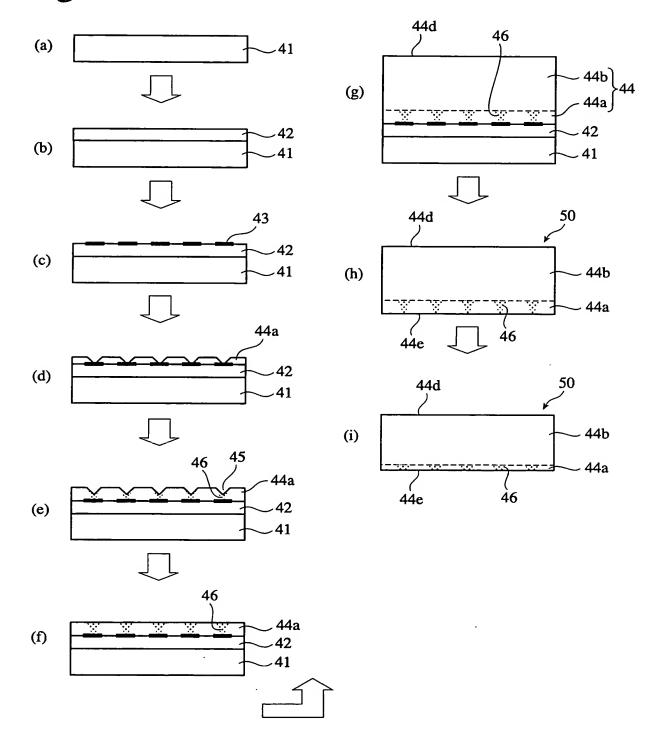


38

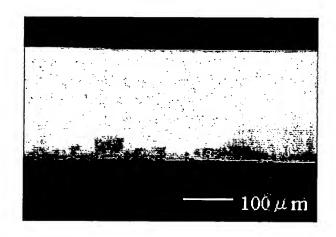
-36b



Masatomo SHIBATA
III-V NITRIDE SEMICONDUCTOR SUBSTRATE
AND ITS PRODUCTION METHOD
Filed: March 31, 2004
SUGHRUE Reference No. Q80822
Sheet 7 of 9



Masatomo SHIBATA
III-V NITRIDE SEMICONDUCTOR SUBSTRATE
AND ITS PRODUCTION METHOD
Filed: March 31, 2004
SUGHRUE Reference No. Q80822
Sheet 8 of 9



Masatomo SHIBATA
III-V NITRIDE SEMICONDUCTOR SUBSTRATE
AND ITS PRODUCTION METHOD
Filed: March 31, 2004
SUGHRUE Reference No. Q80822
Sheet of 9

